



GA20SICP12-247 Information



For Reference Only

Part Number GA20SICP12-247

Manufacturer GeneSiC Semiconductor

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Single

Description TRANS SJT 1200V 45A TO247

Package TO-247-3

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









GA20SICP12-247 Specifications

Manufacturer Part Number	GA20SICP12-247
Manufacturer	GeneSiC Semiconductor
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-247-3
Series	-
FET Type	-
Technology	SiC (Silicon Carbide Junction Transistor)
Drain to Source Voltage (Vdss)	1200V
Current - Continuous Drain (Id) @ 25°C	45A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	-
Vgs(th) (Max) @ Id	-
Gate Charge (Qg) (Max) @ Vgs	-
Input Capacitance (Ciss) (Max) @ Vds	3091pF @ 800V
Vgs (Max)	-
FET Feature	-
Power Dissipation (Max)	282W (Tc)
Rds On (Max) @ Id, Vgs	50 mOhm @ 20A
Operating Temperature	-55°C ~ 175°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-247AB
Package / Case	TO-247-3
	Report errors?

GA20SICP12-247 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

GA20SICP12-247 Payment Methods



















GA20SICP12-247 Shipping Methods













If you have any question about GA20SICP12-247, please do not hesitate to contact us!

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